

LM3880 Three-Rail Simple Power Supply Sequencer

1 Features

- Simple solution for sequencing three voltage rails from a single input signal
- Easily cascade up to three devices to sequence as many as nine voltage rails
- Powerup and powerdown control
- Tiny 2.9-mm x 1.6-mm footprint
- Low quiescent current: 25 µA
- Input voltage range: 2.7 V to 5.5 V
- Standard timing options available

2 Applications

- Advanced driver assistance systems (ADAS)
- Automotive camera modules
- Security cameras
- Servers
- Networking elements
- FPGA power supply sequencing
- Microprocessor and microcontroller sequencing
- Multiple supply sequencing

3 Description

The LM3880 simple power supply sequencer offers the easiest method to control powerup sequencing and powerdown sequencing of multiple Independent voltage rails. By staggering the startup sequence, it is possible to avoid latch conditions or large in-rush currents that can affect the reliability of the system.

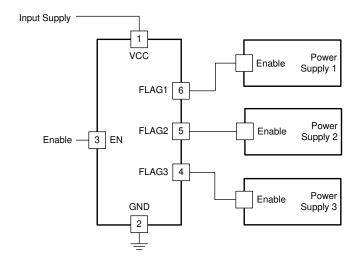
Available in a 6-pin SOT-23 package, the simple sequencer contains a precision enable pin and three open-drain output flags. The open-drain output flags permit that they can be pulled up to distinct voltage supplies separate from the sequencer V_{DD} (only if they do not exceed the recommended maximum voltage of 0.3 V greater than V_{DD}), so as to interface with ICs requiring a range of different enable signals. When the LM3880 is enabled, the three output flags sequentially release, after individual time delays, thus permitting the connected power supplies to start up. The output flags follow a reverse sequence during power down to avoid latch conditions.

EPROM capability allows every delay and sequence to be fully adjustable. Contact Texas Instruments to request a non-standard configuration.

Device Information (1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)	
LM3880	DBV SOT (6)	2.90 mm × 1.60 mm	

For all available packages, see the orderable addendum at the end of the datasheet.



Simple Power Supply Sequencing



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Specified device dimensions in Features section		
Updated application curve titles		14
Changes from Revision K (February 2016) to Revision		Page
Updated Features section to specify how many rails	, , , , , , , , , , , , , , , , , , ,	
Added feature that devices can be cascaded		
 Specified device dimensions in Features section 		1
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Added note in description about open drain FLAG pir		
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· · · · · · · · · · · · · · · · · · ·	(August 2014) ection, Device Functional Modes, Application and	
Added Handling Rating table, Feature Description se	(August 2014) ection, Device Functional Modes, Application and ations section, Layout section, Device and	Page
Added Handling Rating table, Feature Description se Implementation section, Power Supply Recommendation	(August 2014) ection, Device Functional Modes, Application and ations section, Layout section, Device and eckaging, and Orderable Information section	Page

5 Pin Configuration and Functions

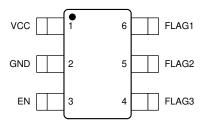


Figure 5-1. DBV Package 6-Pin SOT-23 Top View

Pin Functions

PIN		I/O ⁽¹⁾	DESCRIPTION
NAME	NO.	1/0(-/	DESCRIPTION
EN	3	I	Precision enable pin
FLAG1	6	0	Open-drain output 1
FLAG2	5	0	Open-drain output 2
FLAG3	4	0	Open-drain output 3
GND	2	G	Ground
VCC	1	I	Input supply

(1) I = input, O = output, G = ground



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted) (1) (2)

	MIN	MAX	UNIT
VCC	-0.3	6	V
EN, FLAG1, FLAG2, FLAG3	-0.3	6	V
Maximum Flag ON current		50	mA
Maximum Junction temperature		150	°C
Lead temperature (Soldering, 5 s)		260	°C
Storage temperature T _{stg}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Section 6.3. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	±2	kV

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
VCC to GND	2.7	5.5	V
EN, FLAG1, FLAG2, FLAG3	-0.3	V _{CC} + 0.3	V
Junction temperature	-40	125	°C

6.4 Thermal Information

		LM3880		
	THERMAL METRIC ⁽¹⁾	DBV (SOT-23)	UNIT	
		6 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	187.6	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	127.4	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	31.5	°C/W	
Ψ_{JT}	Junction-to-top characterization parameter	23.3	°C/W	
ΨЈВ	Junction-to-board characterization parameter	31.0	°C/W	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

⁽²⁾ If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

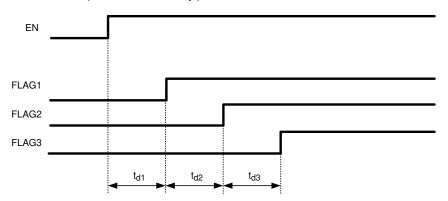
6.5 Electrical Characteristics

Limits apply to all timing options and V_{CC} = 3.3 V, unless otherwise specified. Minimum and Maximum limits apply over the full Operating Temperature Range (T_J = -40°C to +125°C) and are specified through test, design or statistical correlation. Typical values represent the most likely parametric norm at T_J = 25°C and are provided for reference purposes only.

	PARAMETER	TEST CONDITIONS	MIN ⁽¹⁾	TYP ⁽²⁾	MAX ⁽¹⁾	UNIT
IQ	Operating Quiescent current			25	80	μΑ
OPEN-DRAI	N FLAGS	,			-	
I _{FLAG}	FLAGx Leakage Current	V _{FLAGx} = 3.3 V		1	20	nA
V _{OL}	FLAGx Output Voltage Low	I _{FLAGx} = 1.2 mA			0.4	V
POWER-UP	SEQUENCE				-	
t _{d1}	Timer delay 1 accuracy	All Other Timing Options	-15%		15%	
		2 ms Timing Option	-20%		20%	
t _{d2}	Timer delay 2 accuracy	All Other Timing Options	-15%		15%	
		2 ms Timing Option	-20%		20%	
t _{d3}	Timer delay 3 accuracy	All Other Timing Options	-15%		15%	
		2 ms Timing Option	-20%		20%	
POWER-DO	WN SEQUENCE				1	
t _{d4}	Timer delay 4 accuracy	All Other Timing Options	-15%		15%	
		2 ms Timing Option	-20%		20%	
t _{d5}	Timer delay 5 accuracy	All Other Timing Options	-15%		15%	
		2 ms Timing Option	-20%		20%	
t _{d6}	Timer delay 6 accuracy	All Other Timing Options	-15%		15%	
		2 ms Timing Option	-20%		20%	
TIMING DEL	AY ERROR				·	
(t _{d(x)} – 400	Ratio of timing delays	For x = 1 or 4	95%		105%	
μs) / t _{d(x+1)}		For x = 1 or 4, 2 ms option	90%		110%	
t _{d(x)} / t _{d(x+1)}	Ratio of timing delays	For x = 2 or 5	95%		105%	
		For x = 2 or 5, 2 ms option	90%		110%	
ENABLE PIN	l	1	1			
V _{EN}	EN pin threshold		1.0	1.25	1.4	V
I _{EN}	EN pin pullup current	V _{EN} = 0 V		7		μA

⁽¹⁾ Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlation using Statistical Quality Control (SQC) methods. The limits are used to calculate the TI average outgoing quality level (AOQL).

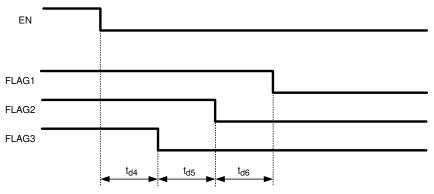
⁽²⁾ Typical numbers are at 25°C and represent the most likely parametric norm.



All standard options use Sequence 1 for output flags rise and fall order. Refer to section 11.1.2 for details of other possible sequences.

Figure 6-1. Timing Requirements





All standard options use Sequence 1 for output flags rise and fall order. Refer to section 11.1.2 for details of other possible sequences.

Figure 6-2. Power-Down Sequence

6.6 Typical Characteristics

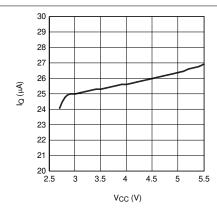
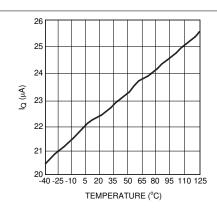


Figure 6-3. Quiescent Current vs Supply Voltage



 V_{CC} = 3.3 V

Figure 6-4. Quiescent Current vs Temperature

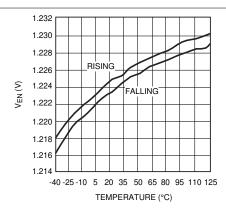
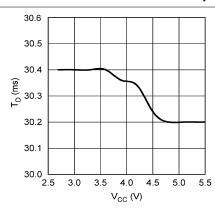


Figure 6-5. Enable Threshold vs Temperature



 $t_{DELAY} = 30 \text{ ms}$

Figure 6-6. Time Delay vs Supply Voltage

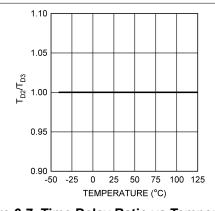
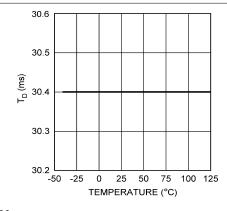


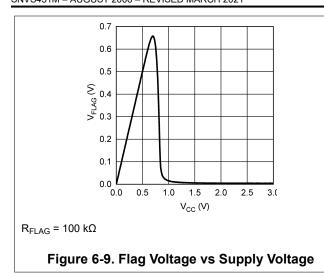
Figure 6-7. Time Delay Ratio vs Temperature



 t_{DELAY} = 30 ms

Figure 6-8. Time Delay vs Temperature





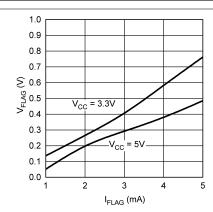


Figure 6-10. Flag Voltage vs Input Current

7 Detailed Description

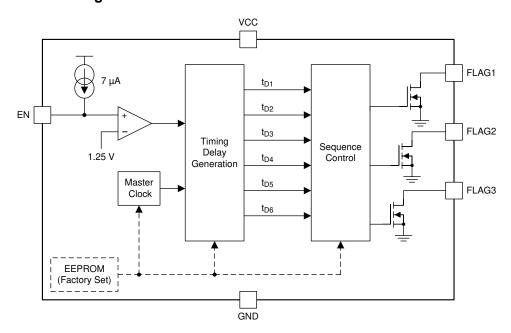
7.1 Overview

The LM3880 simple power supply sequencer provides a simple solution for sequencing multiple rails in a controlled manner. Six independent timers are integrated to control the timing sequence (power up and power down) of three open-drain output flags. These flags permit connection to either a shutdown or enable pin of linear regulators and switchers to control the operation of the power supplies. This allows design of a complete power system without concern for large inrush currents or latch-up conditions that can occur.

The timing sequence of the device is controlled entirely by the enable (EN) pin. Upon power up, all the flags are held low until this precision enable is pulled high. When the EN pin is asserted, the power-up sequence starts. An internal counter delays the first flag (FLAG1) from rising until a fixed time period has expired. When the first flag is released, another timer will begin to delay the release of the second flag (FLAG2). This process repeats until all three flags have sequentially been released.

The power-down sequence is the same as power-up sequence, but in reverse. When the EN pin is deasserted a timer will begin that delays the third flag (FLAG3) from pulling low. The second and first flag will then follow in a sequential manner after their appropriate delays. The three timers that are used to control the power-down scheme can also be individually programmed and are completely independent of the power-up timers.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Enable Pin Operation

The timing sequence of the LM3880 is controlled by the assertion of the enable signal. The enable pin is designed with an internal comparator, referenced to a bandgap voltage (1.25 V), to provide a precision threshold. This allows a delayed timing to be externally set using a capacitor or to start the sequencing based on a certain event, such as a line voltage reaching 90% of nominal. For an additional delayed sequence from the rail powering VCC, simply attach a capacitor to the EN pin as shown in Figure 7-1.



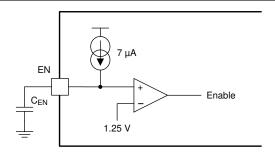


Figure 7-1. Capacitor Timing

Using the internal pullup current source to charge the external capacitor (C_{EN}) the enable pin delay can be calculated by Equation 1:

$$t_{\text{enable_delay}} = \frac{1.25 \text{V x C}_{\text{EN}}}{7 \,\mu\text{A}} \tag{1}$$

A resistor divider can also be used to enable the device based on a certain voltage threshold. Take care when sizing the resistor divider to include the effects of the internal current source.

One of the features of the EN pin is that it provides glitch free operation. The first timer will start counting at a rising threshold, but will always reset if the EN pin is deasserted before the first output flag is released. This can be shown in Figure 7-2:

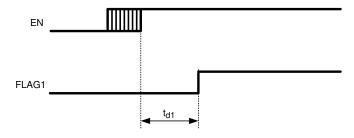


Figure 7-2. EN Glitch

7.3.2 Incomplete Sequence Operation

If the enable signal remains high for the entire power-up sequence, then the part will operate as shown in the standard timing diagrams. However, if the enable signal is de-asserted before the power-up sequence is completed the part will enter a controlled shutdown. This allows the system to walk through a controlled power cycling, preventing any latch conditions from occurring. This state only occurs if the enable pin is deasserted after the completion of timer 1, but before the entire power-up sequence is completed.

When this event occurs, the falling edge of EN pin resets the current timer and will allow the remaining power-up cycle to complete before beginning the power-down sequence. The power down sequence starts approximately 120 ms after the final power-up flag. This allows output voltages in the system to stabilize before everything is shut down. Figure 7-3 shows this operation.

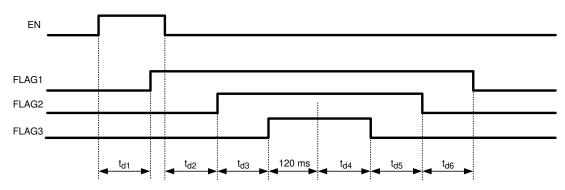


Figure 7-3. Incomplete Power-Up Sequence

When the enable signal is deasserted, the part will commence its power-down sequence. If the enable signal is pulled high before the power-down sequence is completed, the part will ensure completion of the power-down sequence before starting power-up. This ensures that the system does not partially power down and power up and helps prevent latch-up events, such as in FPGAs and microprocessors. This state only occurs if the enable pin is pulled high after the completion of timer 1, but before the entire power-down sequence is completed.

When this event occurs, the rising edge of enable pin resets the current timer and will allow the remaining power-down cycle to complete before beginning the power-up sequence. The power-up sequence starts approximately 120 ms after the final power-down flag. This allows the system to fully shut down before it is powered up. Figure 7-4 shows this operation.

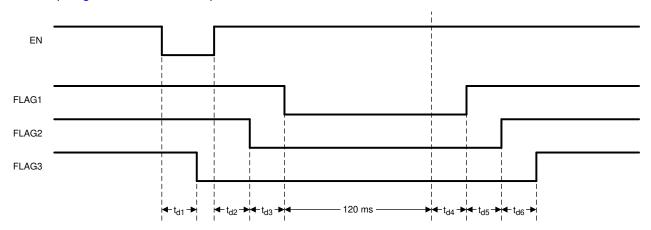


Figure 7-4. Incomplete Power-Down Sequence

All the internal timers are generated by a master clock that has an extremely low tempco. This allows for tight accuracy across temperature and a consistent ratio between the individual timers. There is a slight additional delay of approximately 400 µs to timers 1 and 4, which is a result of the EPROM refresh. This refresh time is in addition to the programmed delay time and will be almost insignificant to all but the shortest of timer delays.



7.4 Device Functional Modes

7.4.1 Power Up With EN Pin

The timing sequence of the Simple Power Supply Sequencer is controlled entirely by the enable (EN) pin. Upon power up, all the flags are held low until this precision enable is pulled high. After the EN pin is asserted, the power-up sequence will commence.

7.4.2 Power Down With EN Pin

When EN pin is deasserted, the power down sequence will commence. A timer will begin that delays the third flag (FLAG3) from pulling low. The second and first flag will then follow in a sequential manner after their appropriate delays.



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Open Drain Flags Pullup

The Simple Power Supply Sequencer contains three open-drain output flags which need to be pulled up for proper operation. $100-k\Omega$ resistors can be used as pullup resistors.

8.1.2 Enable the Device

See Section 7.3.1.

8.2 Typical Application

8.2.1 Simple Sequencing of Three Power Supplies

The Simple Power Supply Sequencer is used to implement a power-up and power-down sequence of three power supplies.

Sequence 1 for the LM3880, e.g. orderable part number LM3880MF-1AA has a power-up sequence (1 - 2 - 3) and power-down sequence (3 - 2 - 1). See Table 10-1 and Table 10-2 for other sequence options or contact TI if other sequence options are desired.

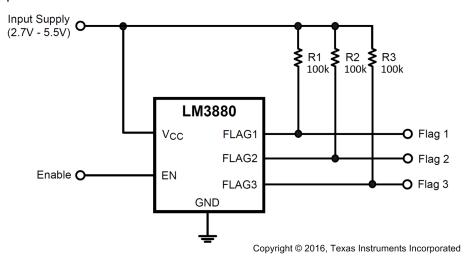


Figure 8-1. Typical Application Circuit



8.2.1.1 Design Requirements

For this design example, use the parameters listed in Table 8-1 as the input parameters. The circuit shown in Figure 8-1 can have various power-down sequences depending on the sequence the part is programmed for. See Table 10-1 for power-down sequence options.

Table 8-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE		
Input Supply voltage range	2.7 V to 5.5 V		
Flag Output voltage, EN high	Input Supply		
Flag Output voltage, EN low	0 V		
Flag Timing Delay	30 ms		
Power-Up Sequence	1 - 2 - 3		
Power-Down Sequence	3 - 2 - 1		

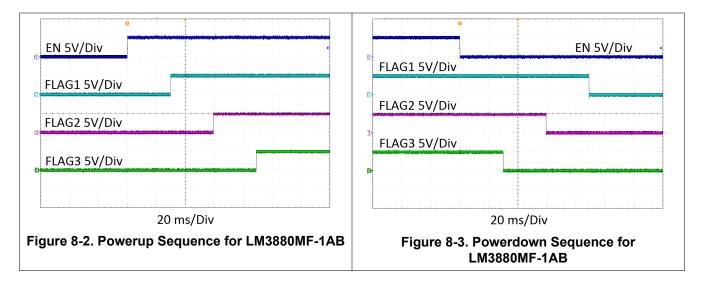
8.2.1.2 Detailed Design Procedure

Table 8-2. List of Materials

DESIGNATOR	DESCRIPTION	DEVICE	QUANTITY	MANUFACTURER
U1	LM3880, Sequence 1, 30 ms timing	LM3880	1	Texas Instruments
R1 100-kΩ Resistor, 0603		CRCW0603100KFKEA	1	Vishay
R2	100-kΩ Resistor, 0603	CRCW0603100KFKEA	1	Vishay
R3	100-kΩ Resistor, 0603	CRCW0603100KFKEA	1	Vishay

This application uses the Sequence 1 and 30-ms timing options of the simple power supply sequencer. See *Section 8.2.1.3* for details on the sequence and timing option.

8.2.1.3 Application Curves



8.2.2 Sequencing Using Independent Flag Supply

For applications requiring a flag output voltage that is different from the VCC, a separate Flag Supply may be used to pullup the open-drain outputs of the simple power supply sequencer. This is useful when interfacing the flag outputs with inputs that require a different voltage than VCC. The designer must ensure the flag supply voltage is not taken above VCC + 0.3 V as specified in the Section 6.3.

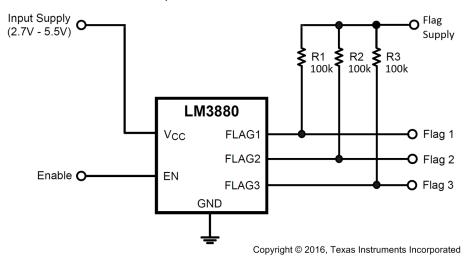


Figure 8-4. Sequencing Using Independent Flag Supply

8.3 Dos and Don'ts

Connecting the EN pin to VCC is not recommended. During powerup sequencing, maintain the EN voltage to a level below the EN voltage threshold until VCC rises above the minimum operating voltage. If EN is connected to VCC, undefined operation at the flag outputs can occur, especially during slow VCC rising slew rates. For systems requiring only powerup sequencing, a capacitor at the EN pin can be used to create a delay or a resistor divider can be used to enable the device based on a certain voltage threshold. While these solutions work for powerup sequencing, it does not powerdown the flag outputs in sequential fashion because the flag outputs simply follow the input supply. For systems requiring both powerup and powerdown sequencing, use an external enable signal, such as a GPIO signal from a microcontroller, to properly control powerup and powerdown of the flag outputs.



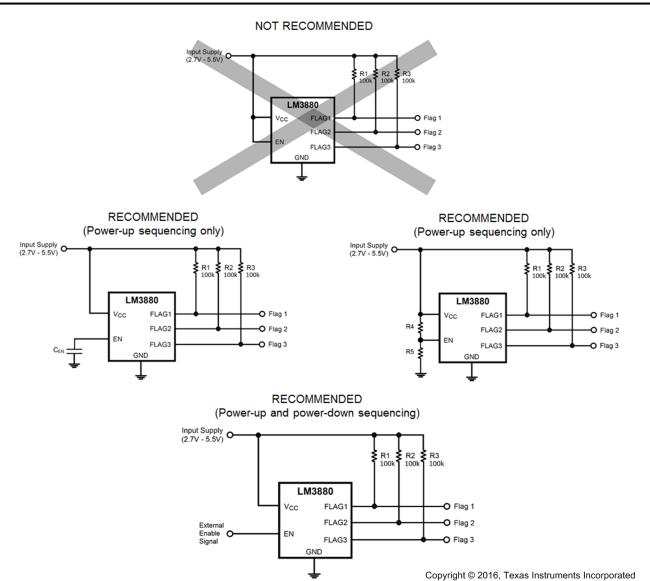


Figure 8-5. Recommended EN Connection



Power Supply Recommendations

The VCC pin should be located as close as possible to the input supply (2.7–5.5 V). An input capacitor is not required but is recommended when noise might be present on the VCC pin. A 0.1- μ F ceramic capacitor may be used to bypass this noise.



9 Layout

9.1 Layout Guidelines

- Pullup resistors should be connected between the flag output pins and a positive input supply, usually VCC. An independent flag supply may also be used. These resistors should be placed as close as possible to the Simple Power Supply Sequencer and the flag supply. Minimal trace length is recommended to make the connections. A typical value for the pullup resistors is $100 \text{ k}\Omega$.
- For very tight sequencing requirements, minimal and equal trace lengths should be used to connect the flag outputs to the desired inputs. This will reduce any propagation delay and timing errors between the flag outputs along the line.

9.2 Layout Example

Figure 9-1 and Figure 9-2 are layout examples for the LM3880. These examples are taken from the LM3880EVAL.

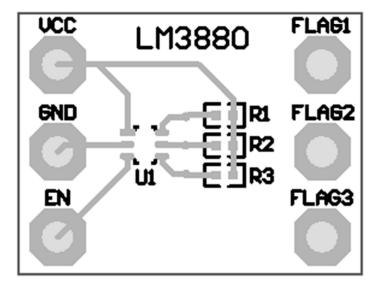


Figure 9-1. LM3880 Top

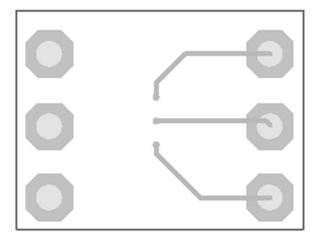


Figure 9-2. LM3880 Bottom

10 Device and Documentation Support

10.1 Device Support

10.1.1 Device Nomenclature

The list of parts available to order appear in the Package Option Addendum.

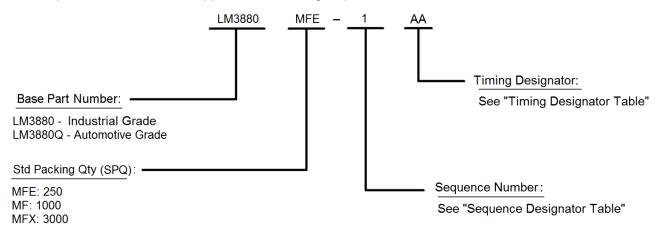


Figure 10-1. Device Nomenclature

Table 10-1. Sequence Designator Table (1)

SECUENCE NUMBER	FLAG ORDER		
SEQUENCE NUMBER	POWER UP	POWER DOWN	
1	1 - 2 - 3	3 - 2 - 1	
2	1 - 2 - 3	3 - 1 - 2	
3	1 - 2 - 3	2 - 3 - 1	
4	1 - 2 - 3	2 - 1 - 3	
5	1 - 2 - 3	1 - 3 - 2	
6	1 - 2 - 3	1 - 2 - 3	

(1) See and Figure 6-2.

Table 10-2. Timing Designator Table (1)

TIMING	DELAYS (ms)					
DESIGNATOR	t _{d1}	t _{d2}	t _{d3}	t _{d4}	t _{d5}	t _{d6}
AA	10	10	10	10	10	10
AB	30	30	30	30	30	30
AC	60	60	60	60	60	60
AD	120	120	120	120	120	120
AE	2	2	2	2	2	2
AF	16	16	16	16	16	16

⁽¹⁾ See and Figure 6-2.

10.2 Community Resources

10.3 Trademarks

All trademarks are the property of their respective owners.



Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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30-Sep-2021

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LM3880MF-1AA	NRND	SOT-23	DBV	6	1000	Non-RoHS & Green	Call TI	Level-1-260C-UNLIM	-40 to 125	F20A	
LM3880MF-1AA/NOPB	ACTIVE	SOT-23	DBV	6	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F20A	Samples
LM3880MF-1AB/NOPB	ACTIVE	SOT-23	DBV	6	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F21A	Samples
LM3880MF-1AC/NOPB	ACTIVE	SOT-23	DBV	6	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F22A	Samples
LM3880MF-1AD/NOPB	ACTIVE	SOT-23	DBV	6	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F23A	Samples
LM3880MF-1AE/NOPB	ACTIVE	SOT-23	DBV	6	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F25A	Samples
LM3880MF-1AF/NOPB	ACTIVE	SOT-23	DBV	6	1000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F31A	Samples
LM3880MFE-1AA/NOPB	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F20A	Samples
LM3880MFE-1AB/NOPB	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F21A	Samples
LM3880MFE-1AC/NOPB	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F22A	Samples
LM3880MFE-1AD/NOPB	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F23A	Samples
LM3880MFE-1AE/NOPB	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F25A	Samples
LM3880MFE-1AF/NOPB	ACTIVE	SOT-23	DBV	6	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F31A	Samples
LM3880MFX-1AA/NOPB	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F20A	Samples
LM3880MFX-1AB/NOPB	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F21A	Samples
LM3880MFX-1AC/NOPB	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F22A	Samples
LM3880MFX-1AD/NOPB	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F23A	Samples
LM3880MFX-1AE/NOPB	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F25A	Samples
LM3880MFX-1AF/NOPB	ACTIVE	SOT-23	DBV	6	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	F31A	Samples

⁽¹⁾ The marketing status values are defined as follows:

PACKAGE OPTION ADDENDUM

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ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF LM3880:

Automotive: LM3880-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM3880MF-1AA	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MF-1AA/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MF-1AB/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MF-1AC/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MF-1AD/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MF-1AE/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MF-1AF/NOPB	SOT-23	DBV	6	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFE-1AA/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFE-1AB/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFE-1AC/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFE-1AD/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFE-1AE/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFE-1AF/NOPB	SOT-23	DBV	6	250	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFX-1AA/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFX-1AB/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFX-1AC/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM3880MFX-1AD/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFX-1AE/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LM3880MFX-1AF/NOPB	SOT-23	DBV	6	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM3880MF-1AA	SOT-23	DBV	6	1000	208.0	191.0	35.0
LM3880MF-1AA/NOPB	SOT-23	DBV	6	1000	208.0	191.0	35.0
LM3880MF-1AB/NOPB	SOT-23	DBV	6	1000	208.0	191.0	35.0
LM3880MF-1AC/NOPB	SOT-23	DBV	6	1000	208.0	191.0	35.0
LM3880MF-1AD/NOPB	SOT-23	DBV	6	1000	208.0	191.0	35.0
LM3880MF-1AE/NOPB	SOT-23	DBV	6	1000	208.0	191.0	35.0
LM3880MF-1AF/NOPB	SOT-23	DBV	6	1000	208.0	191.0	35.0
LM3880MFE-1AA/NOPB	SOT-23	DBV	6	250	208.0	191.0	35.0
LM3880MFE-1AB/NOPB	SOT-23	DBV	6	250	208.0	191.0	35.0
LM3880MFE-1AC/NOPB	SOT-23	DBV	6	250	208.0	191.0	35.0
LM3880MFE-1AD/NOPB	SOT-23	DBV	6	250	208.0	191.0	35.0
LM3880MFE-1AE/NOPB	SOT-23	DBV	6	250	208.0	191.0	35.0
LM3880MFE-1AF/NOPB	SOT-23	DBV	6	250	208.0	191.0	35.0
LM3880MFX-1AA/NOPB	SOT-23	DBV	6	3000	208.0	191.0	35.0
LM3880MFX-1AB/NOPB	SOT-23	DBV	6	3000	208.0	191.0	35.0
LM3880MFX-1AC/NOPB	SOT-23	DBV	6	3000	208.0	191.0	35.0
LM3880MFX-1AD/NOPB	SOT-23	DBV	6	3000	208.0	191.0	35.0
LM3880MFX-1AE/NOPB	SOT-23	DBV	6	3000	208.0	191.0	35.0



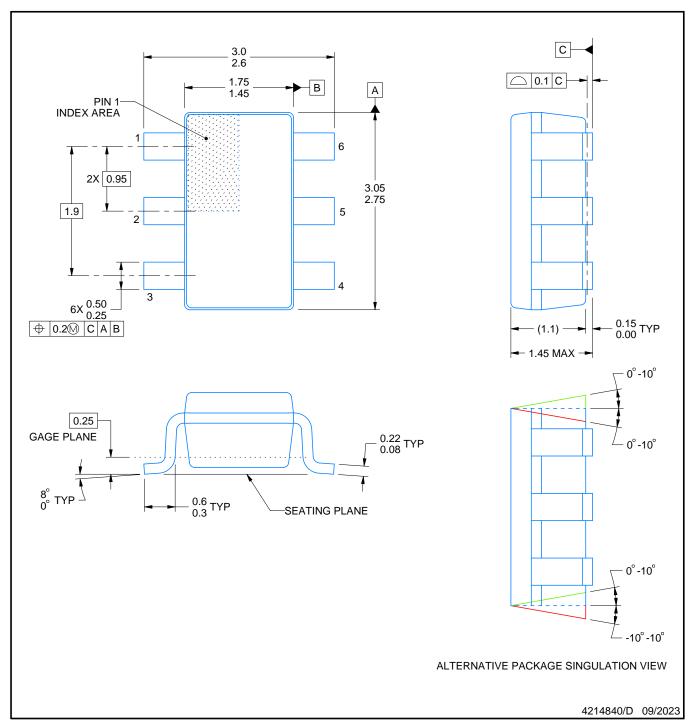
PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM3880MFX-1AF/NOPB	SOT-23	DBV	6	3000	208.0	191.0	35.0



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

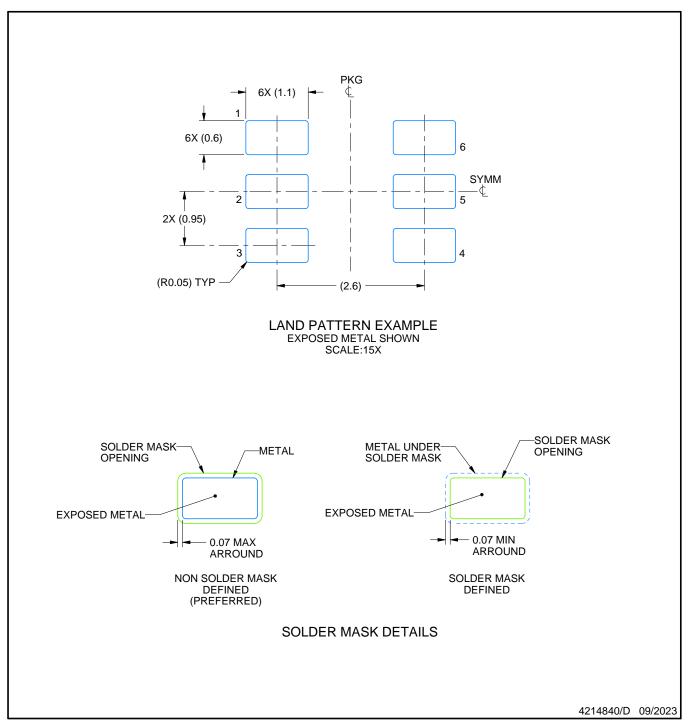
 2. This drawing is subject to change without notice.

 3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.

- 4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- 5. Refernce JEDEC MO-178.



SMALL OUTLINE TRANSISTOR



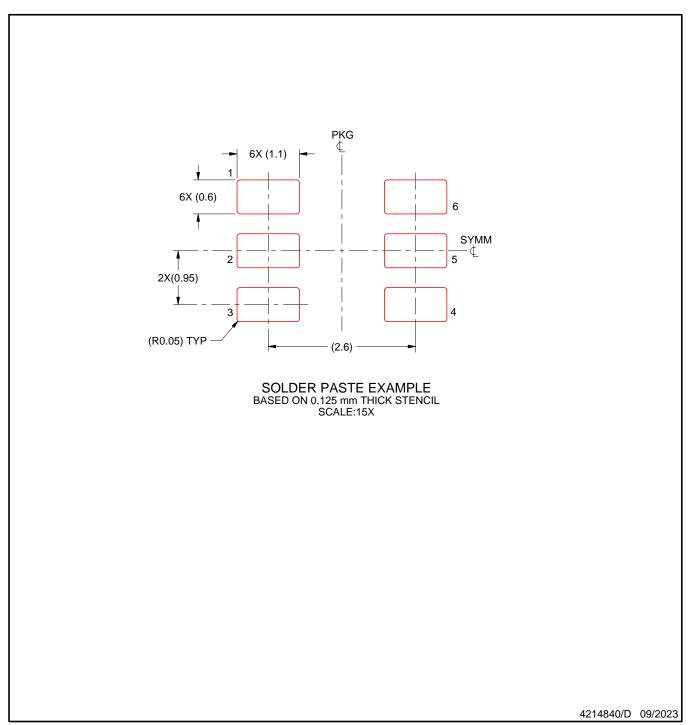
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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